

## 2N7002KW

## Power MOSFET

# 300mA, 60V N-CHANNEL ENHANCEMENT MODE MOSFET

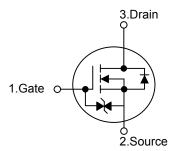
#### DESCRIPTION

The UTC **2N7002KW** uses advanced technology to provide excellent  $R_{DS(ON)}$ , low gate charge and low gate voltages during operation. This device is suitable for use as a load switch or in PWM applications.

#### FEATURES

- \* Low Reverse Transfer Capacitance
- \* ESD Protected
- \* Fast Switching Capability
- \* Avalanche Energy Specified
- \* Improved dv/dt Capability, High Ruggedness

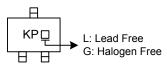
#### SYMBOL

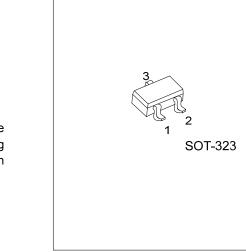


ORDERING INFORMATION

Ordering Number		Deekage	Pin Assignment			Decking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
2N7002KWL-AL3-R	2KWL-AL3-R 2N7002KWG-AL3-R		G	S	D	Tape Reel	
Note: Pin Assignment: G: Gate S: Source D: Drain							
2N7002KWG- <u>AL3-R</u>	<ul> <li>(1)Packing Type</li> <li>(2)Package Type</li> <li>(3)Green Package</li> </ul>	(1) R: Tape Reel (2) AL3: SOT-32: (3) G: Halogen F	3	d Lead	Free, L	: Lead Free	

#### MARKING





### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C, unless otherwise specified.)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V <sub>DSS</sub>	60	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Drain Current	Continuous		300	
	Pulse(Note 2)	ID	800	mA
Power Dissipation			200	mW
Derating above T <sub>A</sub> =25°C		P <sub>D</sub>	1.6	mW/°C
Junction Temperature		TJ	+150	°C
Storage Temperature		T <sub>STG</sub>	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C, unless otherwise specified.)

		1			r	
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	<sub>S</sub> V <sub>GS</sub> =0V, Ι <sub>D</sub> =10μΑ				V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V			1.0	μA
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{DS}=0V, V_{GS}=\pm 20V$			±10	μA
ON CHARACTERISTICS						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250µA	1.0		2.5	V
		V <sub>GS</sub> =10V, I <sub>D</sub> =300mA			4.0	Ω
Static Drain-Source On-Resistance (Note)	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =50mA			6.0	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C <sub>ISS</sub>			22	50	рF
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHz		9	25	pF
Reverse Transfer Capacitance	C <sub>RSS</sub>			4	5.0	pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	t <sub>D(ON)</sub>	I <sub>D</sub> =0.2 A, V <sub>DD</sub> =30V, V <sub>GS</sub> =10V,		1.3	20	ns
Turn-OFF Delay Time	t <sub>D(OFF)</sub>	R <sub>L</sub> =150Ω, R <sub>G</sub> =10Ω		4.2	30	ns
DRAIN-SOURCE DIODE CHARACTERIST	ICS AND MA	XIMUM RATINGS				
Maximum Continuous Drain-Source Diode	ls				300	mA
Forward Current	IS				300	ШA
Maximum Pulsed Drain-Source Diode	I <sub>SM</sub>				0.8	А
Forward Current	ISM				0.0	A
Drain-Source Diode Forward Voltage	$V_{\text{SD}}$	V <sub>GS</sub> =0V, I <sub>S</sub> =300mA (Note)		0.88	1.5	V

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.

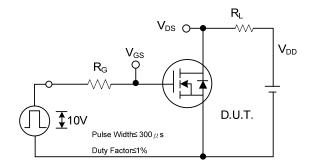
2. Pulse width  ${\leq}300\mu s,$  Duty cycle  ${\leq}1\%$ 



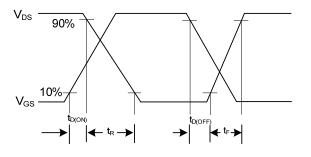
# 2N7002KW

## **Power MOSFET**

### TEST CIRCUITS AND WAVEFORMS



Switching Test Circuit

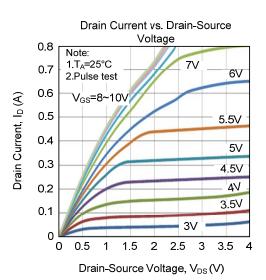


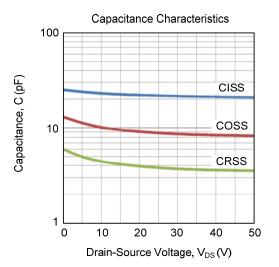
Switching Waveforms

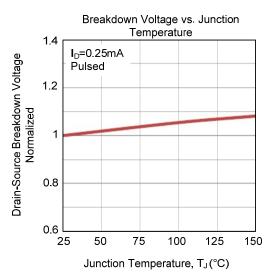


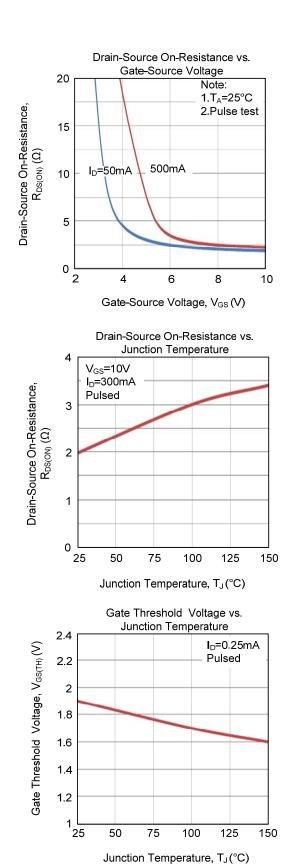
# 2N7002KW

### TYPICAL CHARACTERISTICS







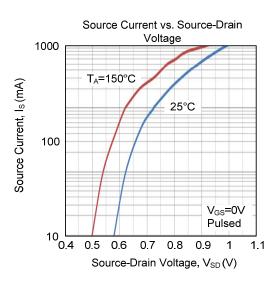


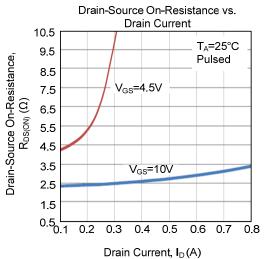


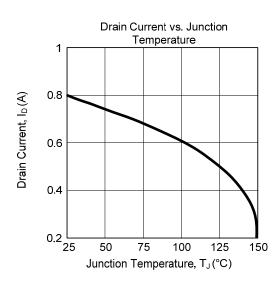
### **Power MOSFET**

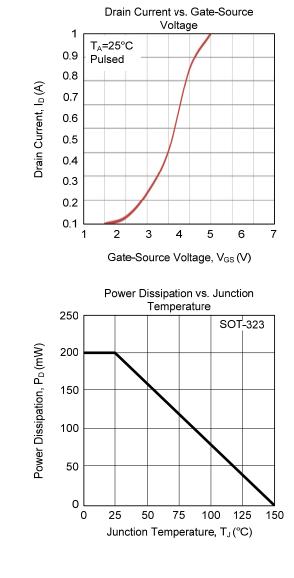
# 2N7002KW

### ■ TYPICAL CHARACTERISTICS (Cont.)









UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

